

High power NPN epitaxial planar bipolar transistor

Features

- High breakdown voltage V_{CEO} = 140 V
- Complementary to 2STW1695
- Fast-switching speed
- Typical f_t = 20 MHz
- Fully characterized at 125 °C

Applications

■ Audio power amplifier

Description

The device is a NPN transistor manufactured using new BiT-LA (Bipolar transistor for linear amplifier) technology. The resulting transistor shows good gain linearity behaviour.

Recommended for 70 W to 100 W high fidelity audio frequency amplifier output stage.

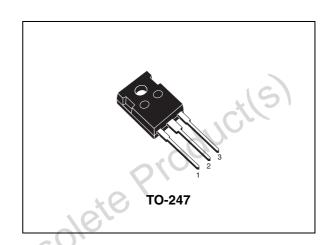


Figure 1. Internal schematic diagram

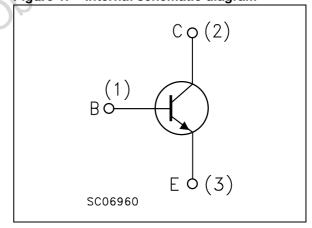


Table 1. Device summary

Order code	Marking	Package	Packaging
2STW4468	2STW4468	TO-247	Tube

Electrical ratings 2STW4468

1 Electrical ratings

Table 2. Absolute maximum rating

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-base voltage (I _E = 0)	200	V
V _{CEO}	Collector-emitter voltage (I _B = 0)	140	V
V _{EBO}	Emitter-base voltage (I _C = 0)	6	V
I _C	Collector current	10	Α
I _{CM}	Collector peak current (t _P < 5 ms)	20	А
P _{tot}	Total dissipation at T _c = 25 °C	100	W
T _{stg}	Storage temperature	-65 to 150	°C
T _J	Max. operating junction temperature	150	°C

Table 3. Thermal data

Obsolete Product(s)

Symbol	Parameter	Value	Unit
R _{thj-case}	Thermal resistance junction-case max	1.25	°C/W

2STW4468 Electrical characteristics

2 Electrical characteristics

 $(T_{case} = 25 \, ^{\circ}C; \, unless \, otherwise \, specified)$

Table 4. Electrical characteristics

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I _{CBO}	Collector cut-off current (I _E = 0)	V _{CB} = 200 V			0.1	μΑ
I _{EBO}	Emitter cut-off current (I _C = 0)	V _{EB} = 6 V			0.1	μА
V _{(BR)CEO} ⁽¹⁾	Collector-emitter breakdown voltage (I _B = 0)	I _C = 50 mA	140		Cill:	٧
V _{(BR)CBO}	Collector-base breakdown voltage (I _E = 0)	I _C = 100 μA	200	0.0		٧
V _{(BR)EBO (1)}	Emitter-base breakdown voltage (I _C = 0)	I _E = 1 mA	6			V
v (1)	Collector-emitter	$I_C = 5 \text{ A}$ $I_B = 500 \text{ mA}$			0.5	V
V _{CE(sat)} (1)	saturation voltage	$I_C = 7 \text{ A}$ $I_B = 700 \text{ mA}$			0.7	V
V_{BE}	Base-emitter voltage	$V_{CE} = 5 V$ $I_C = 5 A$			1.3	V
h	DC ourrent goin	$I_C = 3 A$ $V_{CE} = 4 V$	70		140	
h _{FE}	DC current gain	$I_C = 5 A$ $V_{CE} = 4 V$	50			
f _T	Transition frequency	$I_C = 0.5 \text{ A}$ $V_{CE} = 12 \text{ V}$		20		MHz
C _{CBO}	Collector-base capacitance (I _E = 0)	V _{CB} = 10 V		150		pF
40,	Resistive Load					_
t _{on}	Turn-on time	$V_{CC} = 60 \text{ V}$ $I_{C} = 5 \text{ A}$		0.22		μs
t _{stg}	Storage time	$I_{B1} = -I_{B2} = 0.5 A$		4.3		μs
t _f	Fall time			0.5		μs

^{1.} Pulse duration = 300 μ s, duty cycle \leq 1.5 %

Electrical characteristics 2STW4468

2.1 Electrical characteristics (curves)

Figure 2. Safe operating area

Figure 3. Output characteristics

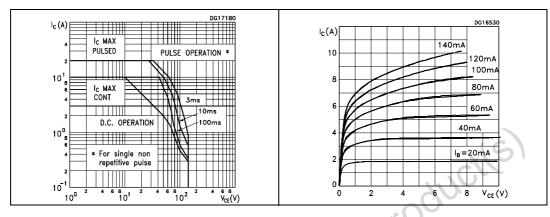


Figure 4. DC current gain

Figure 5. Collector-emitter saturation voltage

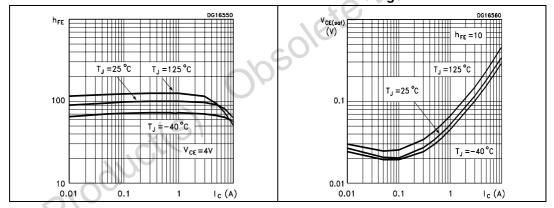
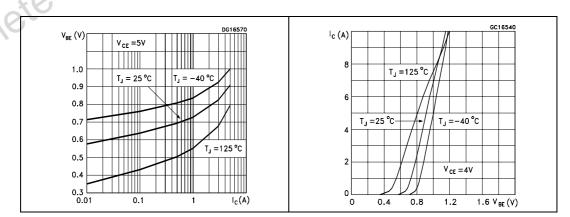


Figure 6. Base-emitter voltage

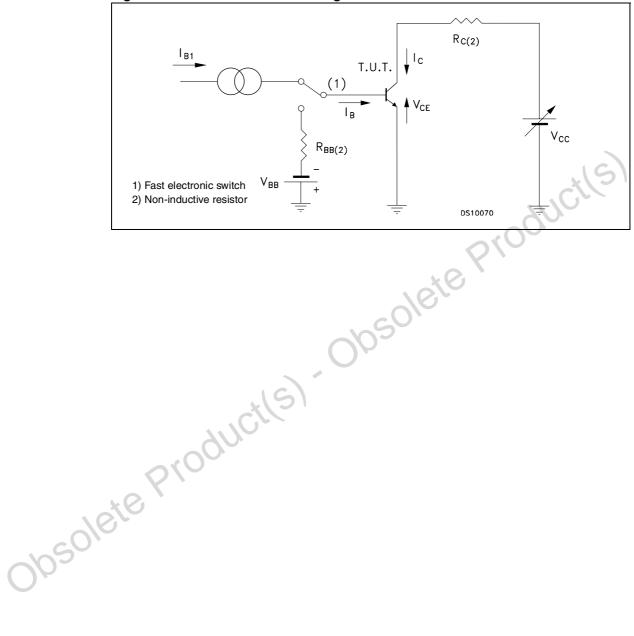
Figure 7. Base-emitter voltage



2STW4468 Electrical characteristics

2.2 Test circuit

Figure 8. Resistive load switching test circuit



3 Package mechanical data

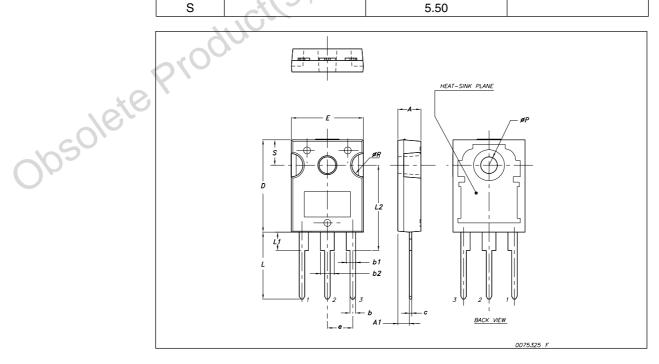
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Obsolete Product(s).

2STW4468

TO-247 Mechanical data

Dim.	mm.				
D iiii.	Min.	Тур	Max.		
Α	4.85		5.15		
A1	2.20	2.60			
b	1.0	1.40			
b1	2.0	2.40			
b2	3.0		3.40		
С	0.40		0.80		
D	19.85	Q.	20.15		
E	15.45	15.75			
е		5.45			
L	14.20	60/	14.80		
L1	3.70	75	4.30		
L2		18.50			
øΡ	3.55		3.65		
øR	4.50		5.50		
S		5.50			



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Revision history 2STW4468

4 Revision history

Table 5. Document revision history

Date	Revision	Changes
23-Oct-2006	1	Initial release
09-Feb-2007	2	New graphics
20-Feb-2007	3	Document status promoted from preliminary data to datasheet.
13-Oct-2008	4	Content reworked to improve readability, no technical changes.
oleteProd	ucils	Content reworked to improve readability, no technical changes.

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